



20A SBR<sup>®</sup> SUPER BARRIER RECTIFIER POWERDI<sup>®</sup>

### **Product Summary**

| ſ | V <sub>RRM</sub> (V) | I <sub>O</sub> (A) | V <sub>F max</sub> (V) | I <sub>R max</sub> (mA) |
|---|----------------------|--------------------|------------------------|-------------------------|
|   | 50                   | 20                 | 0.52                   | 0.5                     |

# **Description and Applications**

Packaged in the compact thermally efficient POWERDI5060-8 package, the SBR20U50SLP provides very low V<sub>F</sub> and excellent reverse leakage stability at high temperatures. It is ideal for use as a rectifier, freewheel diode or blocking diode in:

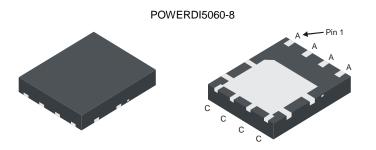
- DC-DC Converters
- AC-DC Adaptors

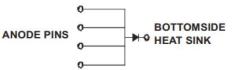
## **Features and Benefits**

- Patented SBR technology provides superior avalanche capability versus schottky diodes, ensuring more rugged and reliable end applications.
- Reduced ultra-low forward voltage drop (V<sub>F</sub>); Better efficiency and cooler operation.
- Reduced high temperature reverse leakage; Increased reliability against thermal runaway failure in high temperature operation.
- <1.1mm Package Profile ideal for thin applications.</li>
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: POWERDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 (3)
- Polarity: See Below
- Weight: 0.097 grams (Approximate)





Note: All four anode pins must be electrically connected at the printed circuit board.

# Ordering Information (Note 4)

| Part Number    | Case          | Packaging         |
|----------------|---------------|-------------------|
| SBR20U50SLP-13 | POWERDI5060-8 | 2,500/Tape & Reel |

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

See http://www.diodes.co and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# Marking Information



SBR20U50S = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 14 = 2014) WW = Week (01-53)

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Notes:



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

| Characteristic  | Symbol                                      | Value | Unit |
|---|---|-------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage              | V <sub>RRM</sub><br>Vrwm<br>V <sub>RM</sub> | 50    | V    |
| RMS Reverse Voltage   | V <sub>R(RMS)</sub>                         | 35    | V    |
| Average Rectified Output Current  | lo  | 20    | A    |
| Non-Repetitive Peak Forward Surge Current 8.3ms<br>Single Half Sine-Wave Superimposed on Rated Load | I <sub>FSM</sub>                            | 100   | A    |

### **Thermal Characteristics**

| Characteristic  | Symbol              | Value       | Unit |
|---|---------------------|-------------|------|
| Typical Thermal Resistance Junction to Ambient (Note 6) | $R_{	ext{	heta}JA}$ | 30          | °C/W |
| Typical Thermal Resistance Junction to Case (Note 6)    | $R_{	ext{	heta}JC}$ | 5           | °C/W |
| Operating and Storage Temperature Range                 | $T_{J,} T_{STG}$    | -55 to +125 | °C   |

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

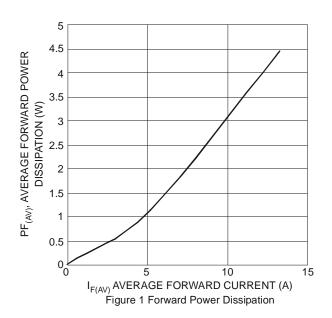
| Characteristic                | Symbol          | Min | Тур  | Max          | Unit | Test Condition   |
|-------------------------------|-----------------|-----|------|--------------|------|--|
| Forward Voltage Drop (Note 8) | VF              | _   | 0.46 | 0.48<br>0.52 | V    | I <sub>F</sub> = 10A, T <sub>J</sub> = +25°C<br>I <sub>F</sub> = 20A, T <sub>J</sub> = +25°C |
| Leakage Current (Note 8)      | I <sub>R</sub>  |     |      | 0.5<br>100   | mA   | $V_R = 50V, T_J = +25^{\circ}C$<br>$V_R = 50V, T_J = +125^{\circ}C$                          |
| Reverse Recovery Time         | t <sub>rr</sub> | —   | 57   | —            | ns   | I <sub>F</sub> = 0.5A, I <sub>R</sub> = 1.0A,<br>I <sub>RR</sub> = 0.25A                     |
| Total Capacitance             | CT              | —   | 400  | —            | pf   | V <sub>R</sub> = 40V, f = 1MHz   |

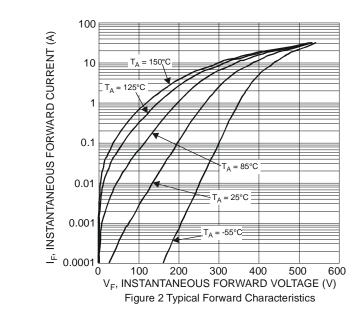
5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.

6. Device mounted on FR4 substrate PC board with 10cm\*10cm copper pad.

7. Device mounted on Aluminum substrate PC board with 2-inch sq. copper pad + additional heatsink (AI 48mm\*35mm\*80mm).

8. Short duration pulse test used to minimize self-heating effect.





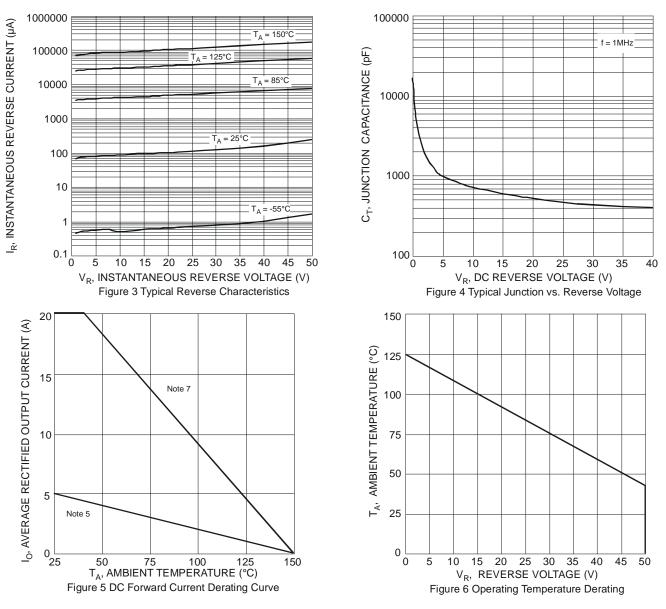
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Notes:



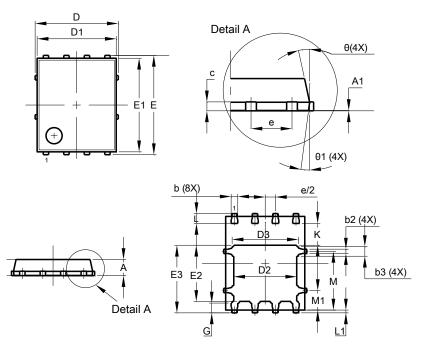
# SBR20U50SLP





## **Package Outline Dimensions**

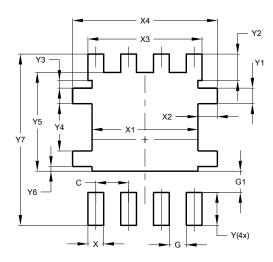
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



|     | POWERDI <sup>®</sup> 5060-8 |           |       |  |  |
|-----|-----------------------------|-----------|-------|--|--|
| Dim | Min                         | Max       | Тур   |  |  |
| Α   | 0.90                        | 1.10      | 1.00  |  |  |
| A1  | 0.00                        | 0.05      | -     |  |  |
| b   | 0.33                        | 0.51      | 0.41  |  |  |
| b2  | 0.200                       | 0.350     | 0.273 |  |  |
| b3  | 0.40                        | 0.80      | 0.60  |  |  |
| С   | 0.230                       | 0.330     | 0.277 |  |  |
| D   |                             | 5.15 BSC  | ;     |  |  |
| D1  | 4.70                        | 5.10      | 4.90  |  |  |
| D2  | 3.70                        | 4.10      | 3.90  |  |  |
| D3  | 3.90                        | 4.30      | 4.10  |  |  |
| E   |                             |           |       |  |  |
| E1  | 5.60                        | 6.00      | 5.80  |  |  |
| E2  | 3.28                        | 3.68      | 3.48  |  |  |
| E3  | 3.99                        | 4.39      | 4.19  |  |  |
| е   | 1.27 BSC                    |           |       |  |  |
| G   | 0.51                        | 0.71      | 0.61  |  |  |
| K   | 0.51                        | -         | -     |  |  |
| L   | 0.51                        | 0.71      | 0.61  |  |  |
| L1  | 0.100                       | 0.200     | 0.175 |  |  |
| M   | 3.235                       | 4.035     | 3.635 |  |  |
| M1  | 1.00                        | 1.40      | 1.21  |  |  |
| θ   | 10°                         | 12º       | 11º   |  |  |
| θ1  | 6º                          | 8º        | 7°    |  |  |
| Al  | Dimens                      | ions in n | າຫ    |  |  |

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С          | 1.270         |
| G          | 0.660         |
| G1         | 0.820         |
| Х          | 0.610         |
| X1         | 4.100         |
| X2         | 0.755         |
| X3         | 4.420         |
| X4         | 5.610         |
| Y          | 1.270         |
| Y1         | 0.600         |
| Y2         | 1.020         |
| Y3         | 0.295         |
| Y4         | 1.825         |
| Y5         | 3.810         |
| Y6         | 0.180         |
| Y7         | 6.610         |



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